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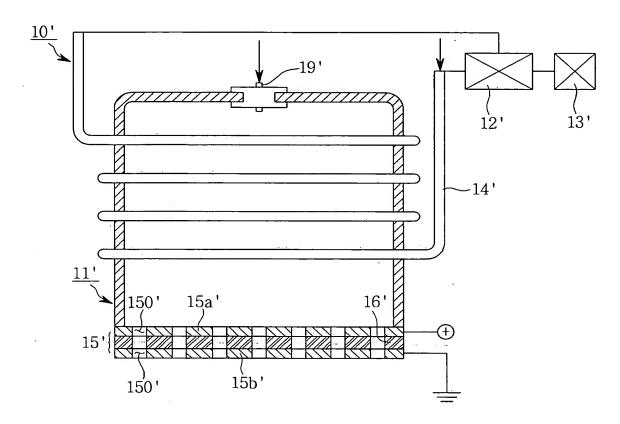
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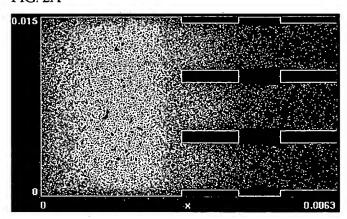
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FIG. 1

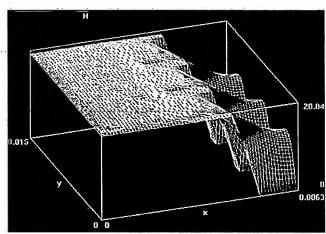


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FIG. 2A

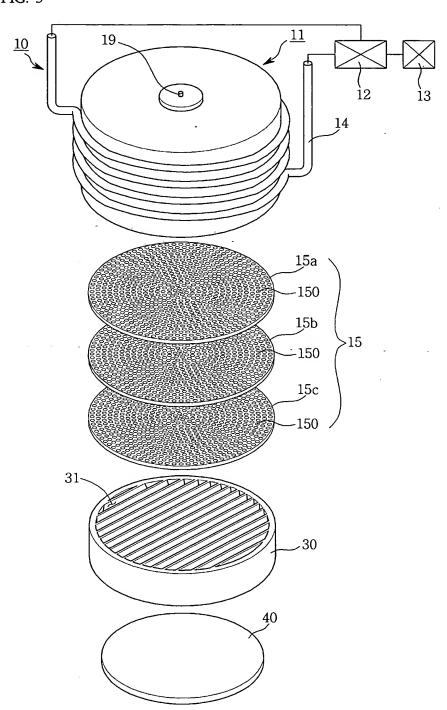


5 FIG. 2B



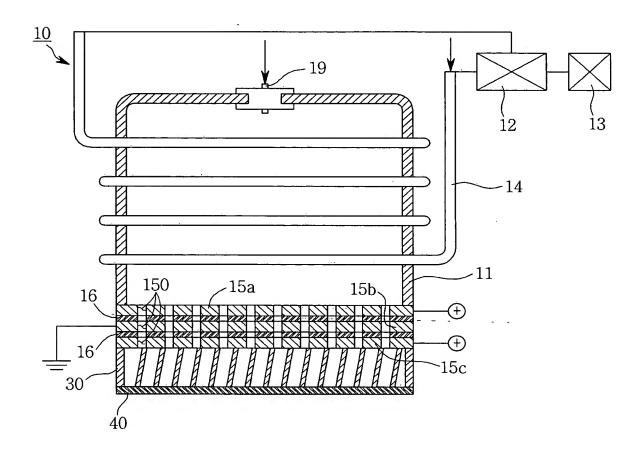
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FIG. 3



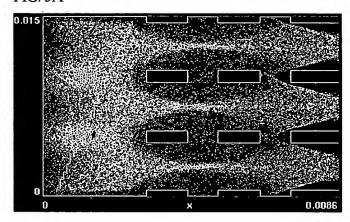
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FIG. 4

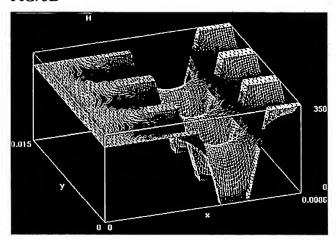


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FIG. 5A

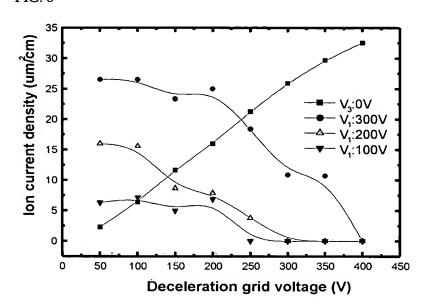


5 FIG. 5B



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FIG. 6



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FIG. 7A

